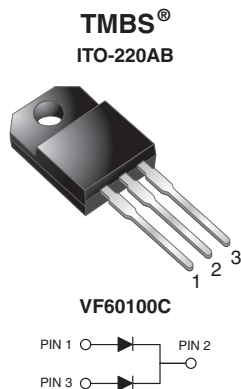


Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.36\text{ V}$ at $I_F = 5\text{ A}$



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- **Halogen-free according to IEC 61249-2-21 definition**



RoHS
COMPLIANT
HALOGEN
FREE

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 30 A
V_{RRM}	100 V
I_{FSM}	320 A
V_F at $I_F = 30\text{ A}$	0.66 V
T_J max.	150 °C

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	VF60100C	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	100	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	per device	60
		per diode	30
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	320	A
Isolation voltage from terminal to heatsink $t = 1$	V_{AC}	1500	V
Voltage rate of change (rated V_R)	dV/dt	10 000	V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	- 40 to + 150	°C



ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	$I_R = 1.0\text{ mA}$	$T_A = 25\text{ }^\circ\text{C}$	V_{BR}	100 (minimum)	-	V
Instantaneous forward voltage per diode	$I_F = 5\text{ A}$	$T_A = 25\text{ }^\circ\text{C}$	$V_F^{(1)}$	0.45	-	V
	$I_F = 10\text{ A}$			0.52	-	
	$I_F = 15\text{ A}$			0.58	0.63	
	$I_F = 20\text{ A}$			0.63	-	
	$I_F = 30\text{ A}$			0.73	0.79	
	$I_F = 5\text{ A}$	$T_A = 125\text{ }^\circ\text{C}$		0.36	-	
	$I_F = 10\text{ A}$			0.45	-	
	$I_F = 15\text{ A}$			0.53	0.58	
	$I_F = 20\text{ A}$			0.58	-	
	$I_F = 30\text{ A}$			0.66	0.70	
Reverse current at rated V_R per diode	$V_R = 80\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$	$I_R^{(2)}$	24	500	μA
		$T_A = 125\text{ }^\circ\text{C}$		13	20	mA
	$V_R = 100\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$		65	1000	μA
		$T_A = 125\text{ }^\circ\text{C}$		30	-	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
 (2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER			SYMBOL	VF60100C	UNIT
Typical thermal resistance	per diode		$R_{\theta JC}$	5.0	$^\circ\text{C/W}$
	per device			3.5	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	VF60100C-M3/4W	1.76	4W	50/tube	Tube



RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

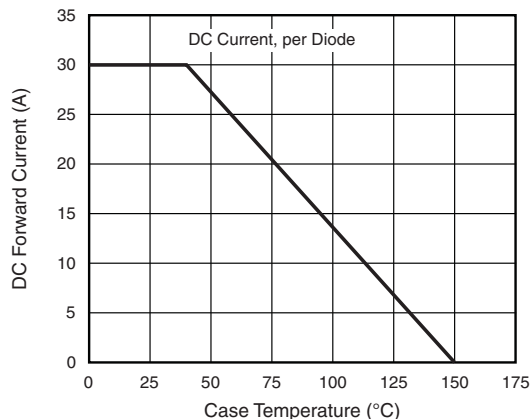


Fig. 1 - Maximum Forward Current Derating Curve

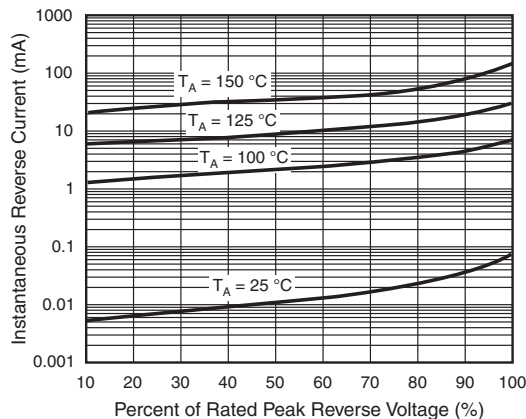


Fig. 4 - Typical Reverse Characteristics Per Diode

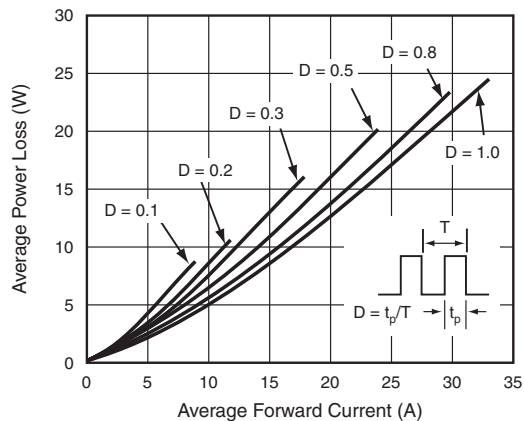


Fig. 2 - Forward Power Loss Characteristics Per Diode

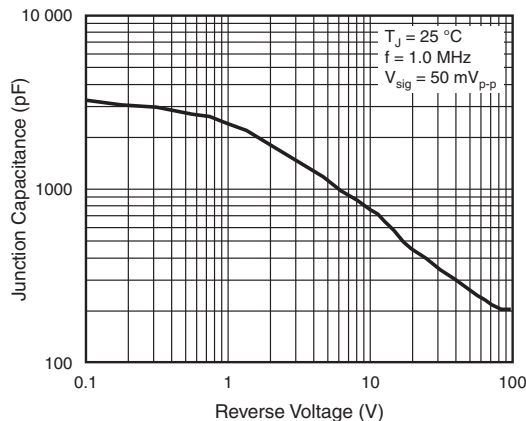


Fig. 5 - Typical Junction Capacitance Per Diode

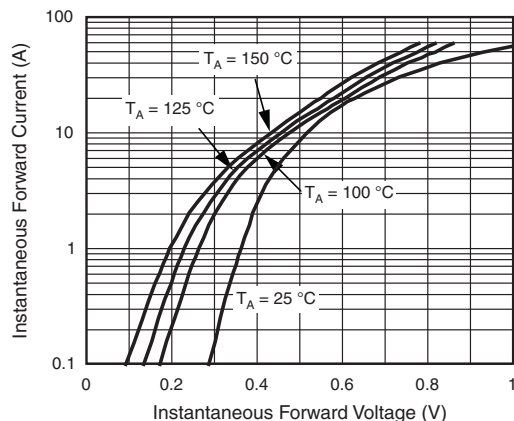
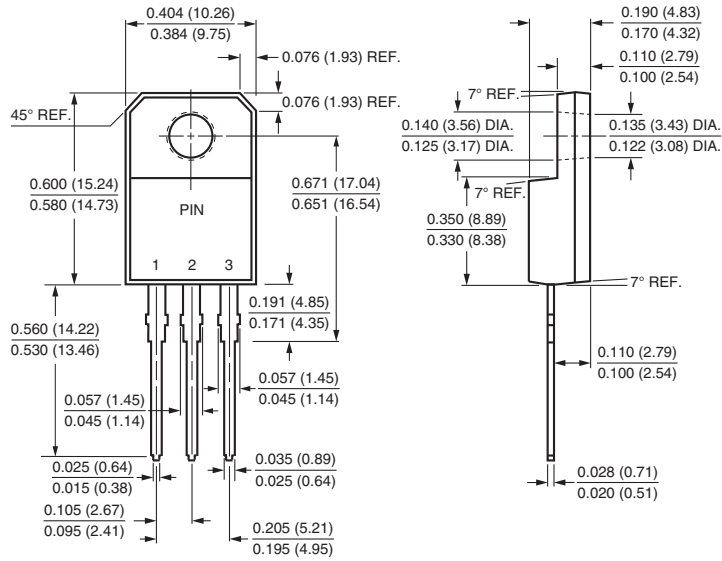


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

ITO-220AB





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